

## TABLE OF CONTENTS

|                                 |   |                                                    |    |
|---------------------------------|---|----------------------------------------------------|----|
| Features .....                  | 1 | Absolute Maximum Ratings .....                     | 7  |
| Applications .....              | 1 | ESD Caution.....                                   | 7  |
| Functional Block Diagrams ..... | 1 | Pin Configurations and Function Descriptions ..... | 8  |
| General Description .....       | 1 | Terminology .....                                  | 10 |
| Product Highlights .....        | 1 | Typical Performance Characteristics .....          | 11 |
| Revision History .....          | 2 | Test Circuits.....                                 | 14 |
| Specifications.....             | 3 | Outline Dimensions .....                           | 16 |
| Dual Supply .....               | 3 | Ordering Guide .....                               | 17 |
| Single Supply .....             | 5 |                                                    |    |

## REVISION HISTORY

### 8/2016—Rev. C to Rev. D

|                                                                                  |    |
|----------------------------------------------------------------------------------|----|
| Changes to Analog Inputs Parameter and Digital Inputs<br>Parameter, Table 3..... | 7  |
| Updated Outline Dimensions .....                                                 | 17 |

### 3/2016—Rev. B to Rev. C

|                                        |    |
|----------------------------------------|----|
| Changes to Figure 5 and Figure 6 ..... | 9  |
| Updated Outline Dimensions .....       | 17 |
| Changes to Ordering Guide .....        | 17 |

### 2/2009—Rev. A to Rev. B

|                                             |    |
|---------------------------------------------|----|
| Change to $I_{DD}$ Parameter, Table 1 ..... | 4  |
| Change to $I_{DD}$ Parameter, Table 2 ..... | 6  |
| Updated Outline Dimensions .....            | 16 |

### 8/2006—Rev. 0 to Rev. A

|                           |            |
|---------------------------|------------|
| Updated Format.....       | \Universal |
| Changes to Table 1 .....  | 13         |
| Changes to Table 2.....   | 14         |
| Changes to Figure 11..... | 110        |
| Changes to Figure 12..... | 111        |

### 1/2006—Revision 0: Initial Version

## SPECIFICATIONS

## DUAL SUPPLY

$V_{DD} = +15\text{ V} \pm 10\%$ ,  $V_{SS} = -15\text{ V} \pm 10\%$ , GND = 0 V, unless otherwise noted.

Table 1.

| Parameter                                                | Y Version <sup>1</sup> |                |                                    | Unit    | Test Conditions/Comments                                                                                                                                                |
|----------------------------------------------------------|------------------------|----------------|------------------------------------|---------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                                          | +25°C                  | −40°C to +85°C | −40°C to +125°C                    |         |                                                                                                                                                                         |
| ANALOG SWITCH                                            |                        |                |                                    |         |                                                                                                                                                                         |
| Analog Signal Range                                      |                        |                | V <sub>SS</sub> to V <sub>DD</sub> | V       | V <sub>S</sub> = ±10 V, I <sub>S</sub> = −1 mA; see Figure 24<br>V <sub>DD</sub> = +13.5 V, V <sub>SS</sub> = −13.5 V<br>V <sub>S</sub> = ±10 V, I <sub>S</sub> = −1 mA |
| On Resistance (R <sub>ON</sub> )                         | 120                    |                |                                    | Ω typ   |                                                                                                                                                                         |
|                                                          | 190                    | 230            | 260                                | Ω max   |                                                                                                                                                                         |
| On Resistance Match Between Channels (ΔR <sub>ON</sub> ) | 3.5                    |                |                                    | Ω typ   |                                                                                                                                                                         |
|                                                          | 6                      | 10             | 12                                 | Ω max   | V <sub>S</sub> = −5 V, 0 V, +5 V; I <sub>S</sub> = −1 mA                                                                                                                |
| On Resistance Flatness (R <sub>FLAT (ON)</sub> )         | 20                     |                |                                    | Ω typ   |                                                                                                                                                                         |
|                                                          | 60                     | 72             | 79                                 | Ω max   |                                                                                                                                                                         |
| LEAKAGE CURRENTS                                         |                        |                |                                    |         |                                                                                                                                                                         |
| Source Off Leakage I <sub>S</sub> (Off)                  | ±0.02                  |                |                                    | nA typ  | V <sub>DD</sub> = +16.5 V, V <sub>SS</sub> = −16.5 V<br>V <sub>D</sub> = ±10 V, V <sub>S</sub> = −10 V; see Figure 25                                                   |
|                                                          | ±0.1                   | ±0.6           | ±1                                 | nA max  |                                                                                                                                                                         |
| Drain Off Leakage I <sub>D</sub> (Off)                   | ±0.02                  |                |                                    | nA typ  | V <sub>S</sub> = 1 V/10 V, V <sub>D</sub> = 10 V/1 V;<br>see Figure 25                                                                                                  |
|                                                          | ±0.1                   | ±0.6           | ±1                                 | nA max  |                                                                                                                                                                         |
| Channel On Leakage I <sub>D</sub> , I <sub>S</sub> (On)  | ±0.02                  |                |                                    | nA typ  | V <sub>S</sub> = V <sub>D</sub> = ±10 V; see Figure 26                                                                                                                  |
|                                                          | ±0.2                   | ±0.6           | ±1                                 | nA max  |                                                                                                                                                                         |
| DIGITAL INPUTS                                           |                        |                |                                    |         |                                                                                                                                                                         |
| Input High Voltage, V <sub>INH</sub>                     |                        |                | 2.0                                | V min   | V <sub>IN</sub> = V <sub>INL</sub> or V <sub>INH</sub>                                                                                                                  |
| Input Low Voltage, V <sub>INL</sub>                      |                        |                | 0.8                                | V max   |                                                                                                                                                                         |
| Input Current                                            |                        |                |                                    |         |                                                                                                                                                                         |
| I <sub>INL</sub> or I <sub>INH</sub>                     | ±0.005                 |                | ±0.1                               | μA typ  |                                                                                                                                                                         |
|                                                          |                        |                |                                    | μA max  |                                                                                                                                                                         |
| Digital Input Capacitance, C <sub>IN</sub>               | 3                      |                |                                    | pF typ  |                                                                                                                                                                         |
| DYNAMIC CHARACTERISTICS <sup>2</sup>                     |                        |                |                                    |         |                                                                                                                                                                         |
| t <sub>TRANSITION</sub>                                  | 110                    |                |                                    | ns typ  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = 10 V; see Figure 27                                                                                  |
|                                                          | 130                    | 150            | 170                                | ns max  |                                                                                                                                                                         |
| t <sub>BBM</sub>                                         | 25                     |                |                                    | ns typ  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S1</sub> = V <sub>S2</sub> = +10 V; see Figure 28                                                              |
|                                                          |                        |                | 10                                 | ns min  |                                                                                                                                                                         |
| t <sub>ON</sub> ( $\overline{\text{EN}}$ )               | 120                    |                |                                    | ns typ  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = 10 V; see Figure 29                                                                                  |
|                                                          | 140                    | 170            | 195                                | ns max  |                                                                                                                                                                         |
| t <sub>OFF</sub> ( $\overline{\text{EN}}$ )              | 40                     |                |                                    | ns typ  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = 10 V; see Figure 29                                                                                  |
|                                                          | 45                     | 55             | 60                                 | ns max  |                                                                                                                                                                         |
| Charge Injection                                         | 0.5                    |                |                                    | pC typ  | V <sub>S</sub> = 0 V, R <sub>S</sub> = 0 Ω, C <sub>L</sub> = 1 nF;<br>see Figure 30                                                                                     |
| Off Isolation                                            | −80                    |                |                                    | dB typ  | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see<br>Figure 31                                                                                               |
| Channel-to-Channel Crosstalk                             | −85                    |                |                                    | dB typ  | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz;<br>see Figure 33                                                                                               |
| Total Harmonic Distortion, THD + N                       | 0.14                   |                |                                    | % typ   | R <sub>L</sub> = 10 kΩ, 5 V rms, f = 20 Hz to<br>20 kHz; see Figure 34                                                                                                  |
| −3 dB Bandwidth                                          | 900                    |                |                                    | MHz typ | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF; see Figure 32                                                                                                             |
| C <sub>S</sub> (Off)                                     | 1.5                    |                |                                    | pF typ  |                                                                                                                                                                         |
|                                                          | 1.7                    |                |                                    | pF max  | f = 1 MHz; V <sub>S</sub> = 0 V                                                                                                                                         |
| C <sub>D</sub> (Off)                                     | 1.6                    |                |                                    | pF typ  | f = 1 MHz; V <sub>S</sub> = 0 V                                                                                                                                         |
|                                                          | 1.8                    |                |                                    | pF max  | f = 1 MHz; V <sub>S</sub> = 0 V                                                                                                                                         |

| Parameter                            | Y Version <sup>1</sup> |                |                 | Unit             | Test Conditions/Comments                                           |
|--------------------------------------|------------------------|----------------|-----------------|------------------|--------------------------------------------------------------------|
|                                      | +25°C                  | –40°C to +85°C | –40°C to +125°C |                  |                                                                    |
| C <sub>D</sub> , C <sub>S</sub> (On) | 3.5<br>4               |                |                 | pF typ<br>pF max | f = 1 MHz; V <sub>S</sub> = 0 V<br>f = 1 MHz; V <sub>S</sub> = 0 V |
| POWER REQUIREMENTS                   |                        |                |                 |                  | V <sub>DD</sub> = +16.5 V, V <sub>SS</sub> = –16.5 V               |
| I <sub>DD</sub>                      | 0.002                  |                | 1.0             | μA typ<br>μA max | Digital inputs = 0 V or V <sub>DD</sub>                            |
| I <sub>DD</sub>                      | 260                    |                | 475             | μA typ<br>μA max | Digital inputs = 5 V                                               |
| I <sub>SS</sub>                      | 0.002                  |                | 1.0             | μA typ<br>μA max | Digital inputs = 0 V or V <sub>DD</sub>                            |
| I <sub>SS</sub>                      | 0.002                  |                | 1.0             | μA typ<br>μA max | Digital inputs = 5 V                                               |
| V <sub>DD</sub> /V <sub>SS</sub>     |                        |                | ±5/±16.5        | V min/max        | GND = 0 V                                                          |

<sup>1</sup> Temperature range for the Y version: –40°C to +125°C.

<sup>2</sup> Guaranteed by design, not subject to production test.

**SINGLE SUPPLY**

$V_{DD} = 12\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$ , unless otherwise noted.

**Table 2.**

| Parameter                                                | Y Version <sup>1</sup> |                |                      | Unit    | Test Conditions/Comments                                                                        |
|----------------------------------------------------------|------------------------|----------------|----------------------|---------|-------------------------------------------------------------------------------------------------|
|                                                          | +25°C                  | −40°C to +85°C | −40°C to +125°C      |         |                                                                                                 |
| ANALOG SWITCH                                            |                        |                |                      |         |                                                                                                 |
| Analog Signal Range                                      |                        |                | 0 to V <sub>DD</sub> | V       |                                                                                                 |
| On Resistance (R <sub>ON</sub> )                         | 300                    |                |                      | Ω typ   | V <sub>S</sub> = 0 V to 10 V, I <sub>S</sub> = −1 mA; see Figure 24                             |
| On Resistance Match Between Channels (ΔR <sub>ON</sub> ) | 475                    | 567            | 625                  | Ω max   | V <sub>DD</sub> = 10.8 V, V <sub>SS</sub> = 0 V                                                 |
|                                                          | 5                      |                |                      | Ω typ   | V <sub>S</sub> = 0 V to 10 V, I <sub>S</sub> = −1 mA                                            |
| On Resistance Flatness (R <sub>FLAT (ON)</sub> )         | 16                     | 26             | 27                   | Ω max   |                                                                                                 |
|                                                          | 60                     |                |                      | Ω typ   | V <sub>S</sub> = 3 V, 6 V, 9 V, I <sub>S</sub> = −1 mA                                          |
| LEAKAGE CURRENTS                                         |                        |                |                      |         |                                                                                                 |
| Source Off Leakage I <sub>S</sub> (Off)                  | ±0.02                  |                |                      | nA typ  | V <sub>DD</sub> = 13.2 V<br>V <sub>S</sub> = 1 V/10 V, V <sub>D</sub> = 10 V/1 V; see Figure 25 |
| Drain Off Leakage I <sub>D</sub> (Off)                   | ±0.1                   | ±0.6           | ±1                   | nA max  |                                                                                                 |
|                                                          | ±0.02                  |                |                      | nA typ  | V <sub>S</sub> = 1 V/10 V, V <sub>D</sub> = 10 V/1 V; see Figure 25                             |
| Channel On Leakage I <sub>D</sub> , I <sub>S</sub> (On)  | ±0.1                   | ±0.6           | ±1                   | nA max  |                                                                                                 |
|                                                          | ±0.02                  |                |                      | nA typ  | V <sub>S</sub> = V <sub>D</sub> = 1 V or 10 V, see Figure 26                                    |
|                                                          | ±0.2                   | ±0.6           | ±1                   | nA max  |                                                                                                 |
| DIGITAL INPUTS                                           |                        |                |                      |         |                                                                                                 |
| Input High Voltage, V <sub>INH</sub>                     |                        |                | 2.0                  | V min   |                                                                                                 |
| Input Low Voltage, V <sub>INL</sub>                      |                        |                | 0.8                  | V max   |                                                                                                 |
| Input Current, I <sub>INL</sub> or I <sub>INH</sub>      | ±0.001                 |                |                      | μA typ  |                                                                                                 |
|                                                          |                        |                | ±0.1                 | μA max  | V <sub>IN</sub> = V <sub>INL</sub> or V <sub>INH</sub>                                          |
| Digital Input Capacitance, C <sub>IN</sub>               | 2                      |                |                      | pF typ  |                                                                                                 |
| DYNAMIC CHARACTERISTICS <sup>2</sup>                     |                        |                |                      |         |                                                                                                 |
| t <sub>TRANSITION</sub>                                  | 135                    |                |                      | ns typ  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF                                                  |
|                                                          | 170                    | 200            | 230                  |         | V <sub>S</sub> = 8 V; see Figure 27                                                             |
| t <sub>BBM</sub>                                         | 45                     |                |                      | ns typ  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF                                                  |
|                                                          |                        |                | 10                   | ns min  | V <sub>S1</sub> = V <sub>S2</sub> = 8 V; see Figure 28                                          |
| t <sub>ON</sub> ( $\overline{\text{EN}}$ )               | 150                    |                |                      | ns typ  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF                                                  |
|                                                          | 195                    | 230            | 265                  |         | V <sub>S</sub> = 8 V; see Figure 29                                                             |
| t <sub>OFF</sub> ( $\overline{\text{EN}}$ )              | 45                     |                |                      | ns typ  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF                                                  |
|                                                          | 60                     | 70             | 75                   |         | V <sub>S</sub> = 8 V; see Figure 29                                                             |
| Charge Injection                                         | −0.3                   |                |                      | pC typ  | V <sub>S</sub> = 6 V, R <sub>S</sub> = 0 Ω, C <sub>L</sub> = 1 nF; see Figure 30                |
| Off Isolation                                            | −80                    |                |                      | dB typ  | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see Figure 31                          |
| Channel-to-Channel Crosstalk                             | −85                    |                |                      | dB typ  | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see Figure 33                          |
| −3 dB Bandwidth                                          | 600                    |                |                      | MHz typ | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF; see Figure 32                                     |
| C <sub>S</sub> (Off)                                     | 1.5                    |                |                      | pF typ  | f = 1 MHz; V <sub>S</sub> = 6 V                                                                 |
|                                                          | 1.7                    |                |                      | pF max  | f = 1 MHz; V <sub>S</sub> = 6 V                                                                 |
| C <sub>D</sub> (Off)                                     | 2                      |                |                      | pF typ  | f = 1 MHz; V <sub>S</sub> = 6 V                                                                 |
|                                                          | 2.2                    |                |                      | pF max  | f = 1 MHz; V <sub>S</sub> = 6 V                                                                 |
| C <sub>D</sub> , C <sub>S</sub> (On)                     | 4                      |                |                      | pF typ  | f = 1 MHz; V <sub>S</sub> = 6 V                                                                 |
|                                                          | 4.5                    |                |                      | pF max  | f = 1 MHz; V <sub>S</sub> = 6 V                                                                 |

| Parameter          | Y Version <sup>1</sup> |                |                 | Unit                                                | Test Conditions/Comments                                     |
|--------------------|------------------------|----------------|-----------------|-----------------------------------------------------|--------------------------------------------------------------|
|                    | +25°C                  | –40°C to +85°C | –40°C to +125°C |                                                     |                                                              |
| POWER REQUIREMENTS |                        |                |                 |                                                     |                                                              |
| $I_{DD}$           | 0.002                  |                | 1.0             | $\mu\text{A typ}$                                   | $V_{DD} = 13.2\text{ V}$<br>Digital inputs = 0 V or $V_{DD}$ |
| $I_{DD}$           | 260                    |                | 475             | $\mu\text{A max}$                                   | Digital inputs = 5 V                                         |
| $V_{DD}$           |                        |                | 5/16.5          | $\mu\text{A typ}$<br>$\mu\text{A max}$<br>V min/max | $V_{SS} = 0\text{ V}$ , GND = 0 V                            |

<sup>1</sup> Temperature range for the Y version: –40°C to +125°C<sup>2</sup> Guaranteed by design, not subject to production test.

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 3.

| Parameter                                                     | Rating                                                                                |
|---------------------------------------------------------------|---------------------------------------------------------------------------------------|
| $V_{DD}$ to $V_{SS}$                                          | 35 V                                                                                  |
| $V_{DD}$ to GND                                               | $-0.3\text{ V to }+25\text{ V}$                                                       |
| $V_{SS}$ to GND                                               | $+0.3\text{ V to }-25\text{ V}$                                                       |
| Analog Inputs <sup>1</sup>                                    | $V_{SS} - 0.3\text{ V to }V_{DD} + 0.3\text{ V}$<br>or 30 mA (whichever occurs first) |
| Digital Inputs                                                | GND $- 0.3\text{ V to }V_{DD} + 0.3\text{ V}$<br>or 30 mA (whichever occurs first)    |
| Continuous Current, S or D                                    | 24 mA                                                                                 |
| Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle Maximum) | 100 mA                                                                                |
| Operating Temperature Range                                   |                                                                                       |
| Automotive Temperature Range (Y Version)                      | $-40^\circ\text{C to }+125^\circ\text{C}$                                             |
| Storage Temperature Range                                     | $-65^\circ\text{C to }+150^\circ\text{C}$                                             |
| Junction Temperature                                          | $150^\circ\text{C}$                                                                   |
| TSSOP, $\theta_{JA}$ , Thermal Impedance                      | $112^\circ\text{C/W}$                                                                 |
| LFCSP, $\theta_{JA}$ , Thermal Impedance                      | $30.4^\circ\text{C/W}$                                                                |
| Reflow Soldering Peak Temperature, Pb-Free                    | $260^\circ\text{C}$                                                                   |

<sup>1</sup> Overvoltages at A,  $\overline{\text{EN}}$ , S, or D are clamped by internal diodes. Current must be limited to the maximum ratings given.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating is applied at any one time.

### ESD CAUTION



#### ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

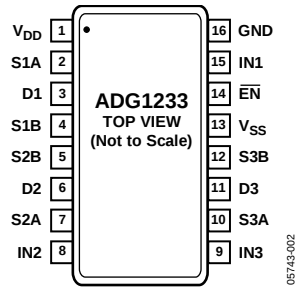


Figure 3. 16-Lead TSSOP Pin Configuration

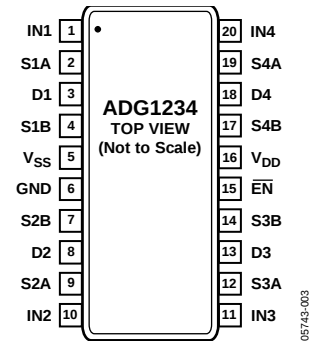


Figure 4. 20-Lead TSSOP Pin Configuration

Table 4. 16-Lead TSSOP/20-Lead TSSOP Pin Configurations

| Pin No. <b>ADG1233</b> 16-Lead TSSOP | Pin No. <b>ADG1234</b> 20-Lead TSSOP | Mnemonic        |
|--------------------------------------|--------------------------------------|-----------------|
| 1                                    | 16                                   | V <sub>DD</sub> |
| 2                                    | 2                                    | S1A             |
| 3                                    | 3                                    | D1              |
| 4                                    | 4                                    | S1B             |
| 5                                    | 7                                    | S2B             |
| 6                                    | 8                                    | D2              |
| 7                                    | 9                                    | S2A             |
| 8                                    | 10                                   | IN2             |
| 9                                    | 11                                   | IN3             |
| 10                                   | 12                                   | S3A             |
| 11                                   | 13                                   | D3              |
| 12                                   | 14                                   | S3B             |
| 13                                   | 5                                    | V <sub>SS</sub> |
| 14                                   | 15                                   | EN              |
| 15                                   | 1                                    | IN1             |
| 16                                   | 6                                    | GND             |
| Not applicable                       | 17                                   | S4B             |
| Not applicable                       | 18                                   | D4              |
| Not applicable                       | 19                                   | S4A             |
| Not applicable                       | 20                                   | IN4             |

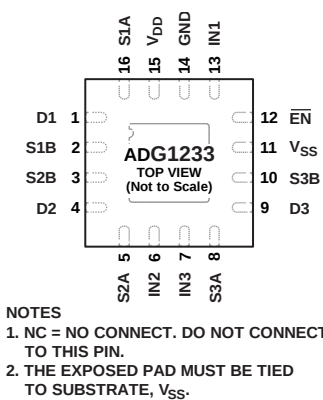


Figure 5. 16-Lead, 4 mm × 4 mm LFCSP Pin Configuration, Exposed Pad Tied to Substrate,  $V_{SS}$

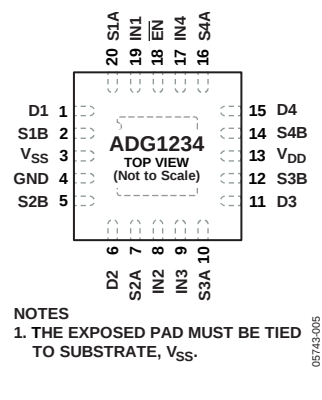


Figure 6. 20-Lead, 4 mm × 4 mm LFCSP Pin Configuration, Exposed Pad Tied to Substrate,  $V_{SS}$

Table 5. 16-Lead LFCSP/20-Lead LFCSP Pin Configurations

| Pin No. <b>ADG1233</b> 16-Lead LFCSP | Pin No. <b>ADG1234</b> 20-Lead LFCSP | Mnemonic |
|--------------------------------------|--------------------------------------|----------|
| 1                                    | 1                                    | D1       |
| 2                                    | 2                                    | S1B      |
| 3                                    | 5                                    | S2B      |
| 4                                    | 6                                    | D2       |
| 5                                    | 7                                    | S2A      |
| 6                                    | 8                                    | IN2      |
| 7                                    | 9                                    | IN3      |
| 8                                    | 10                                   | S3A      |
| 9                                    | 11                                   | D3       |
| 10                                   | 12                                   | S3B      |
| 11                                   | 3                                    | $V_{SS}$ |
| 12                                   | 18                                   | EN       |
| 13                                   | 19                                   | IN1      |
| 14                                   | 4                                    | GND      |
| 15                                   | 13                                   | $V_{DD}$ |
| 16                                   | 20                                   | S1A      |
| Not applicable                       | 14                                   | S4B      |
| Not applicable                       | 15                                   | D4       |
| Not applicable                       | 16                                   | S4A      |
| Not applicable                       | 17                                   | IN4      |

Table 6. **ADG1233/ADG1234** Truth Table

| EN | INx | Switch xA | Switch xB |
|----|-----|-----------|-----------|
| 1  | X   | Off       | Off       |
| 0  | 0   | Off       | On        |
| 0  | 1   | On        | Off       |

## TERMINOLOGY

**V<sub>DD</sub>**

Most positive supply potential.

**V<sub>SS</sub>**

Most negative power supply potential in dual supplies. In single-supply applications, it can be connected to ground.

**GND**

Ground (0 V) reference.

**R<sub>ON</sub>**

Ohmic resistance between D and S.

**ΔR<sub>ON</sub>**

Difference between the R<sub>ON</sub> of any two channels.

**I<sub>S</sub> (Off)**

Source leakage current when switch is off.

**I<sub>D</sub> (Off)**

Drain leakage current when switch is off.

**I<sub>D</sub>, I<sub>S</sub> (On)**

Channel leakage current when switch is on.

**V<sub>D</sub>, V<sub>S</sub>**

Analog voltage on Terminal D, Terminal S.

**C<sub>S</sub> (Off)**

Channel input capacitance for off condition.

**C<sub>D</sub> (Off)**

Channel output capacitance for off condition.

**C<sub>D</sub>, C<sub>S</sub> (On)**

On switch capacitance.

**C<sub>IN</sub>**

Digital input capacitance.

**t<sub>ON</sub> ( $\overline{\text{EN}}$ )**

Delay time between the 50% and 90% points of the digital input and switch on condition.

**t<sub>OFF</sub> ( $\overline{\text{EN}}$ )**

Delay time between the 50% and 90% points of the digital input and switch off condition.

**t<sub>TRANSITION</sub>**

Delay time between the 50% and 90% points of the digital inputs and the switch on condition when switching from one address state to another.

**t<sub>BBM</sub>**

Off time measured between the 80% point of both switches when switching from one address state to another.

**V<sub>INL</sub>**

Maximum input voltage for Logic 0.

**V<sub>INH</sub>**

Minimum input voltage for Logic 1.

**I<sub>INL</sub>, I<sub>INH</sub>**

Input current of the digital input.

**I<sub>DD</sub>**

Positive supply current.

**I<sub>SS</sub>**

Negative supply current.

### Off Isolation

A measure of an unwanted signal coupling through an off channel.

### Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

### Bandwidth

Frequency at which the output is attenuated by 3 dB.

### On Response

Frequency response of the on switch.

### THD + N

Ratio of the harmonic amplitude plus noise of the signal to the fundamental.

## TYPICAL PERFORMANCE CHARACTERISTICS

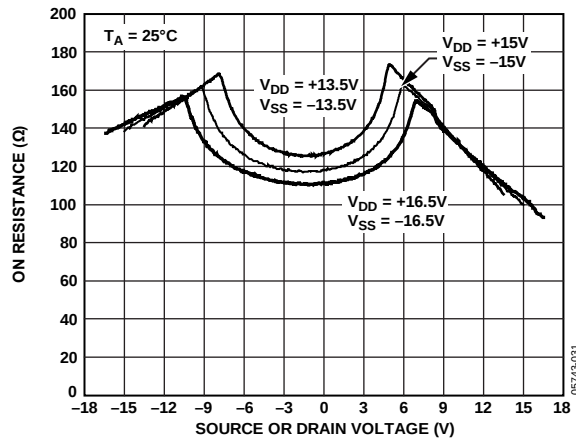
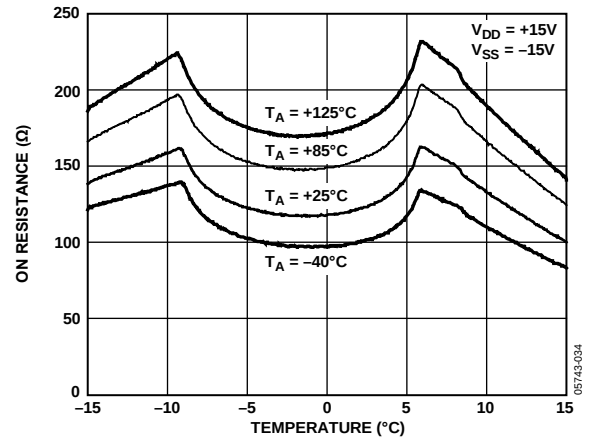
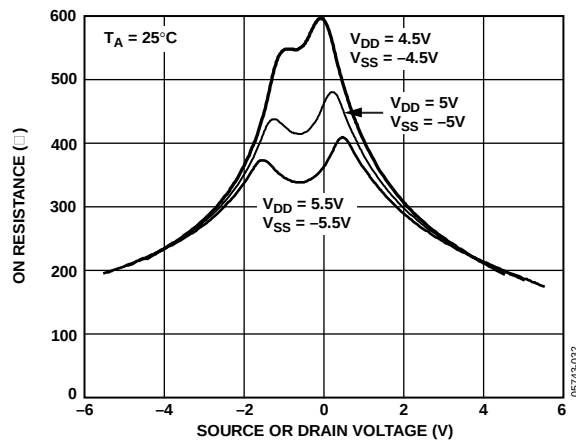
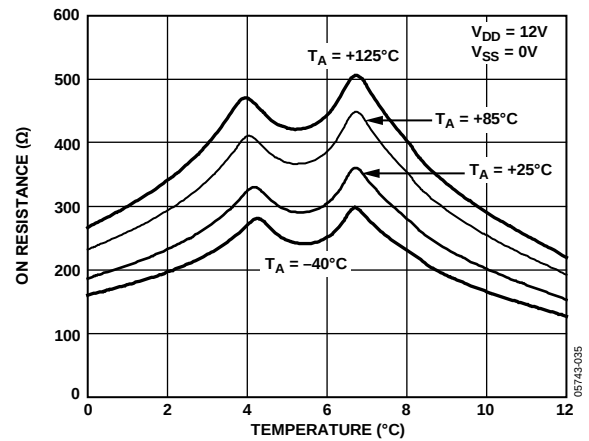
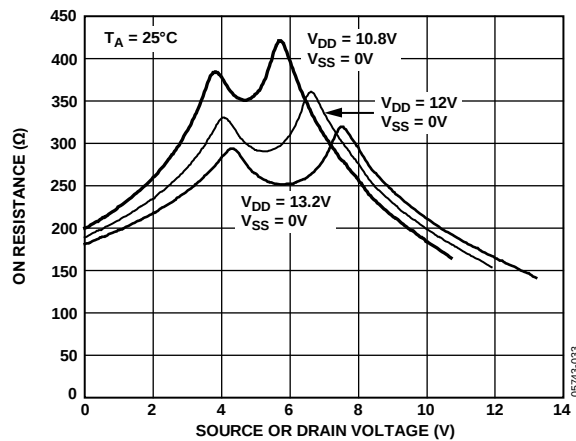
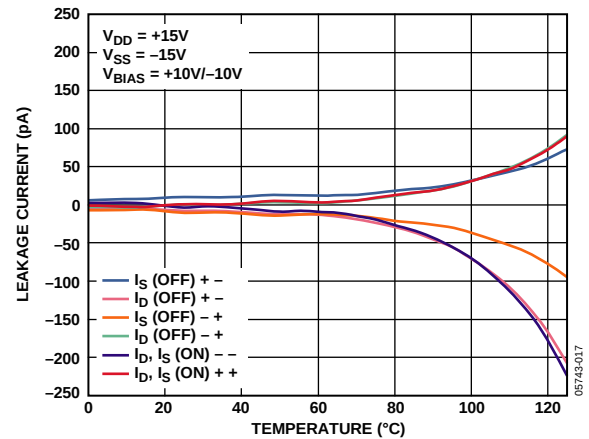
Figure 7. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Dual SupplyFigure 10. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures, Dual SupplyFigure 8. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Dual SupplyFigure 11. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures, Single SupplyFigure 9. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Single Supply

Figure 12. Leakage Currents as a Function of Temperature, Dual Supply

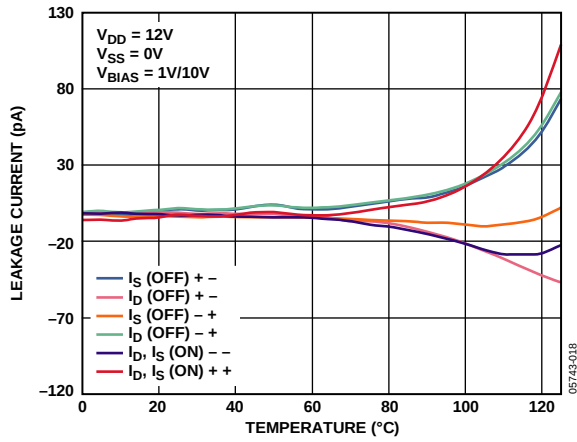


Figure 13. Leakage Currents as a Function of Temperature, Single Supply

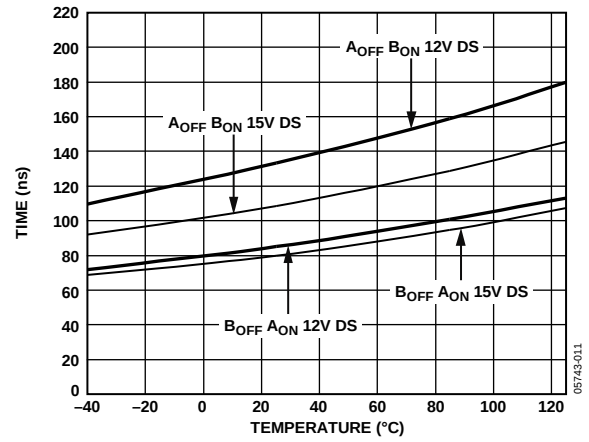


Figure 16.  $t_{\text{TRANSITION}}$  vs. Temperature

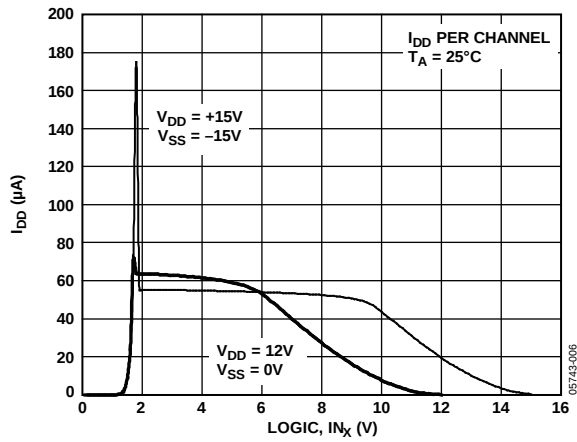


Figure 14.  $I_{\text{DD}}$  vs. Logic Level

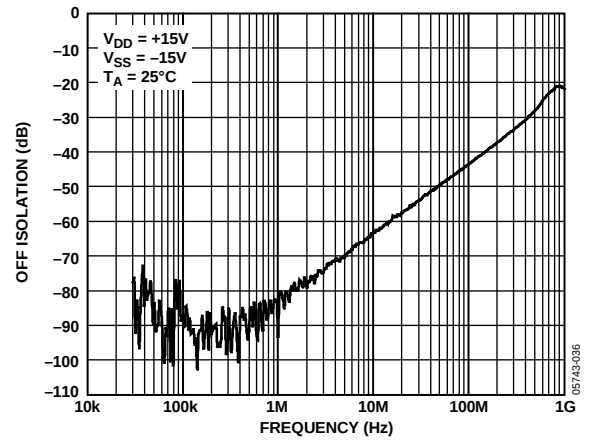


Figure 17. Off Isolation vs. Frequency

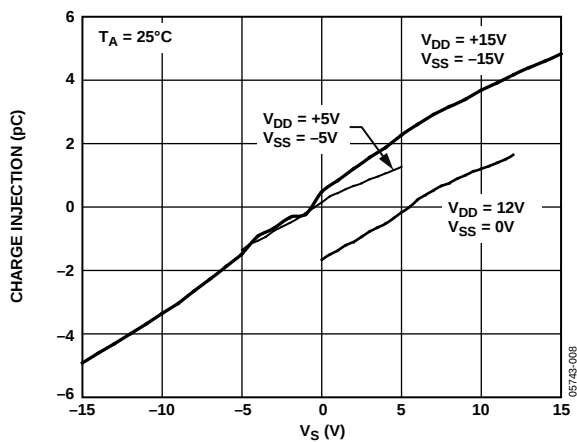


Figure 15. Charge Injection vs. Source Voltage

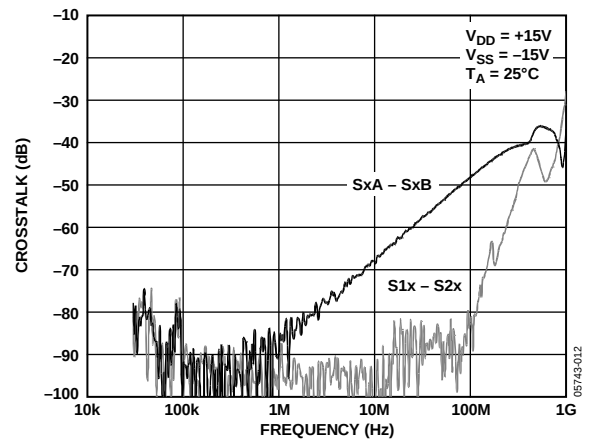


Figure 18. Crosstalk vs. Frequency

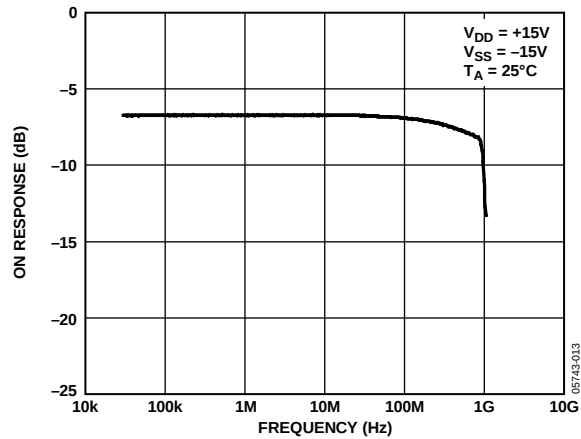


Figure 19. On Response vs. Frequency

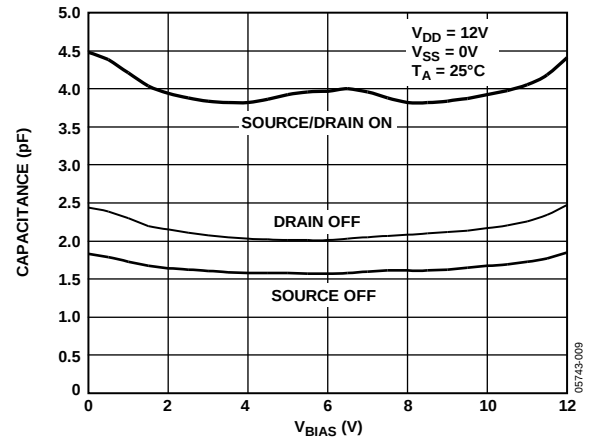


Figure 22. Capacitance vs. Source Voltage for Single Supply

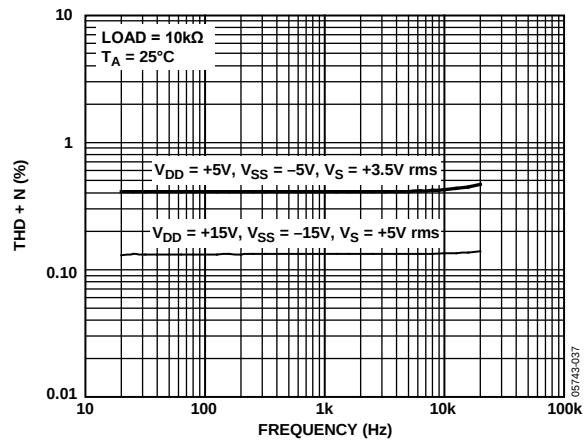


Figure 20. THD + N vs. Frequency

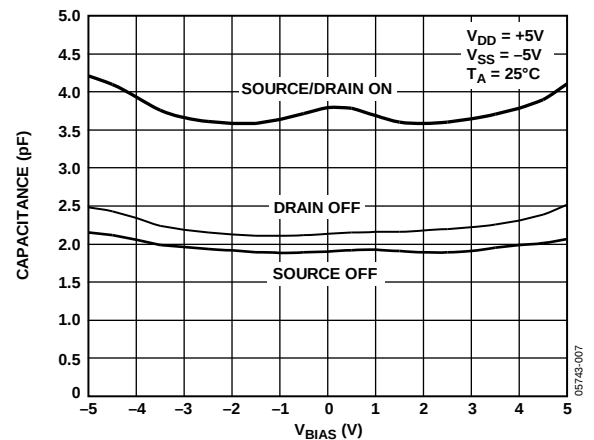


Figure 23. Capacitance vs. Source Voltage for Dual Supply

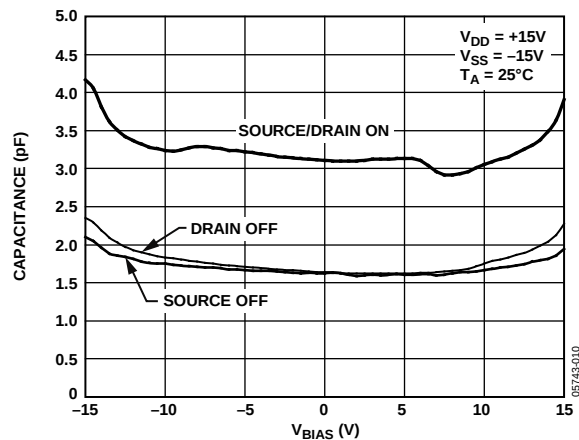


Figure 21. Capacitance vs. Source Voltage for Dual Supply

## TEST CIRCUITS

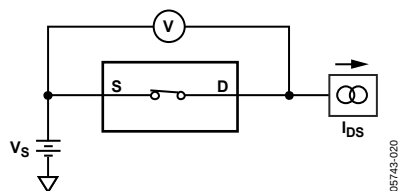


Figure 24. On Resistance

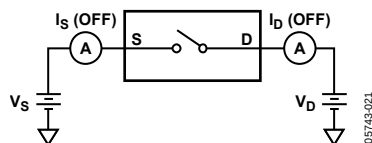


Figure 25. Off Leakage

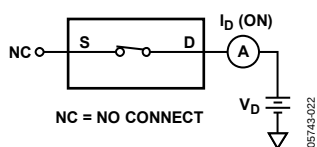


Figure 26. On Leakage

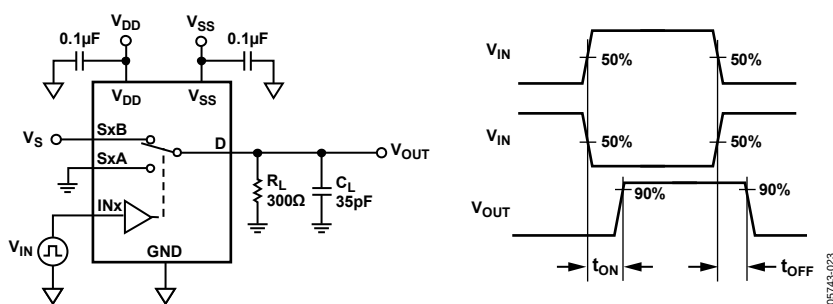


Figure 27. Switching Timing

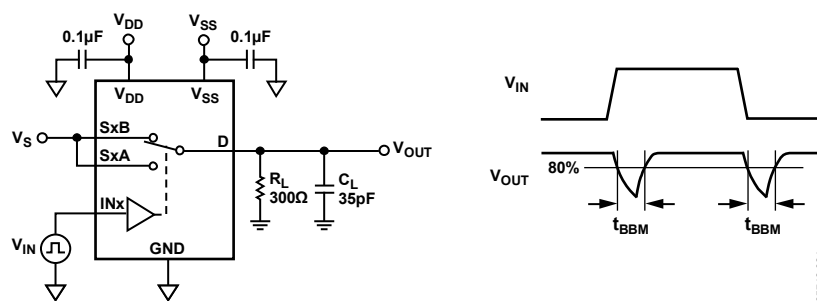


Figure 28. Break-Before-Make Delay

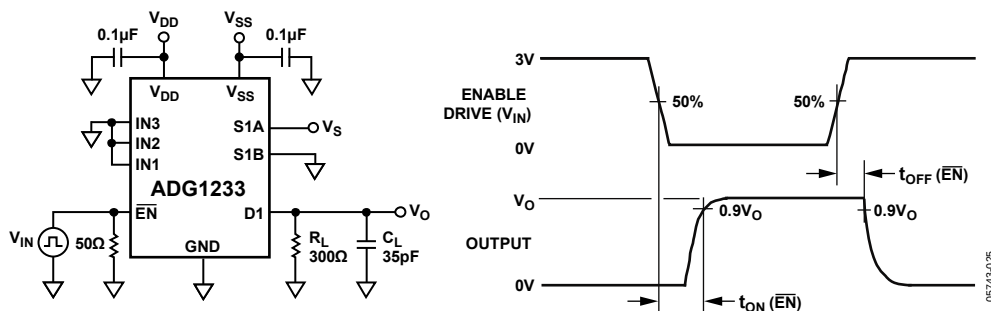
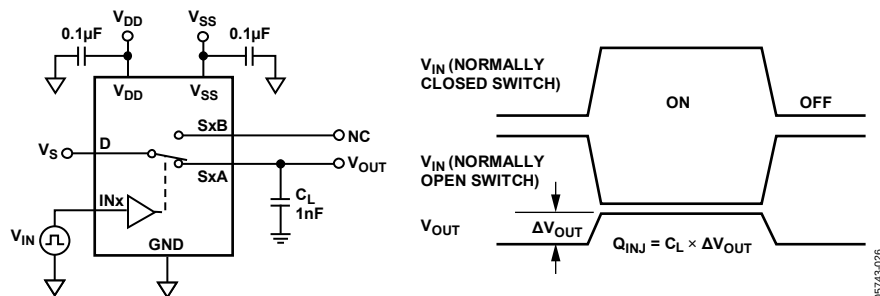
Figure 29. Enable Delay,  $t_{ON}(\overline{EN})$ ,  $t_{OFF}(\overline{EN})$ 

Figure 30. Charge Injection

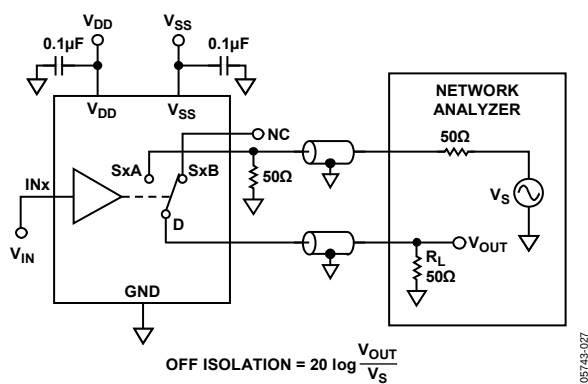


Figure 31. Off Isolation

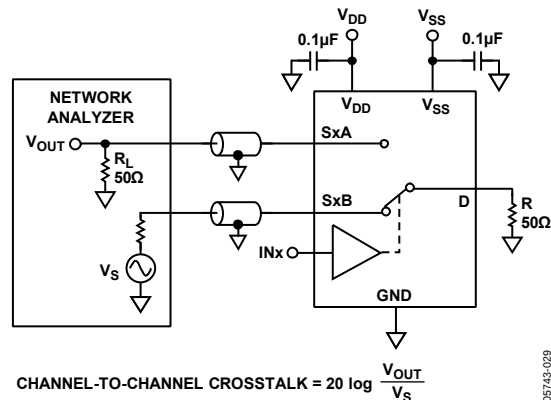


Figure 33. Channel-to-Channel Crosstalk

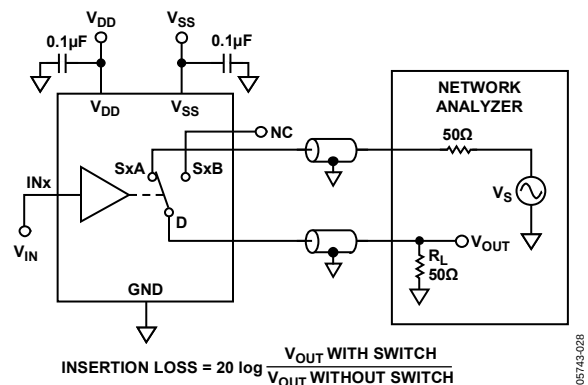


Figure 32. Bandwidth

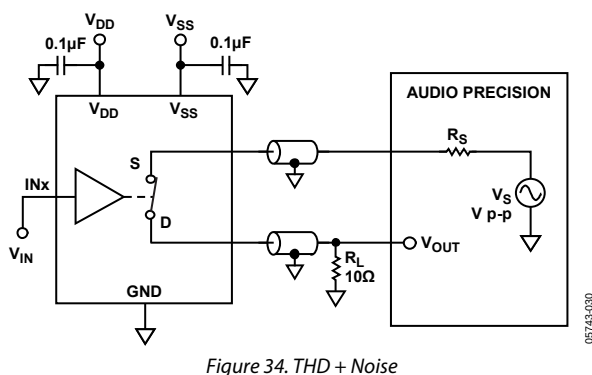
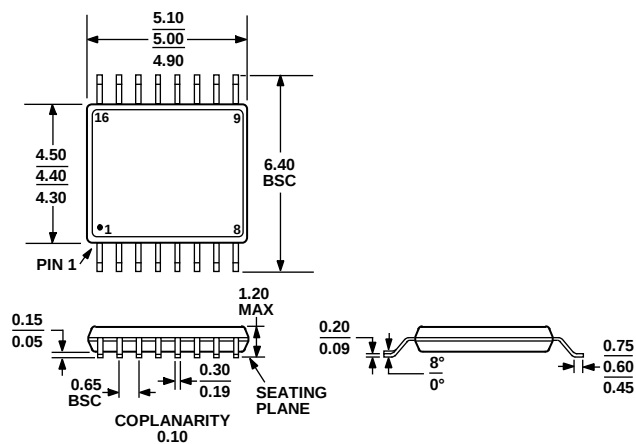


Figure 34. THD + Noise

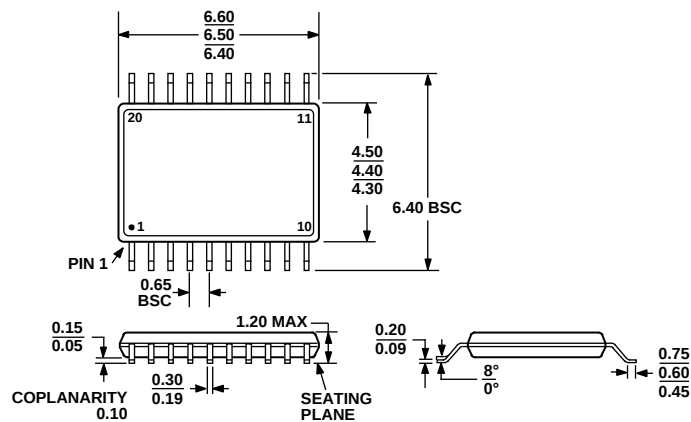
## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AB

Figure 35. 16-Lead Thin Shrink Small Outline Package [TSSOP] (RU-16)

Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-153-AC

Figure 36. 20-Lead Thin Shrink Small Outline Package [TSSOP] (RU-20)

Dimensions shown in millimeters

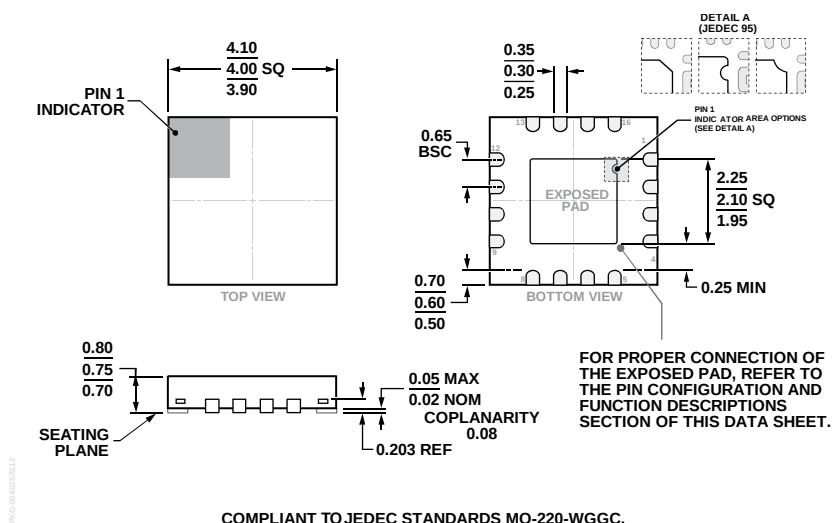


Figure 37. 16-Lead Lead Frame Chip Scale Package [LFCSP]  
4 mm × 4 mm Body and 0.75 mm Package Height  
(CP-16-23)

Dimensions shown in millimeters

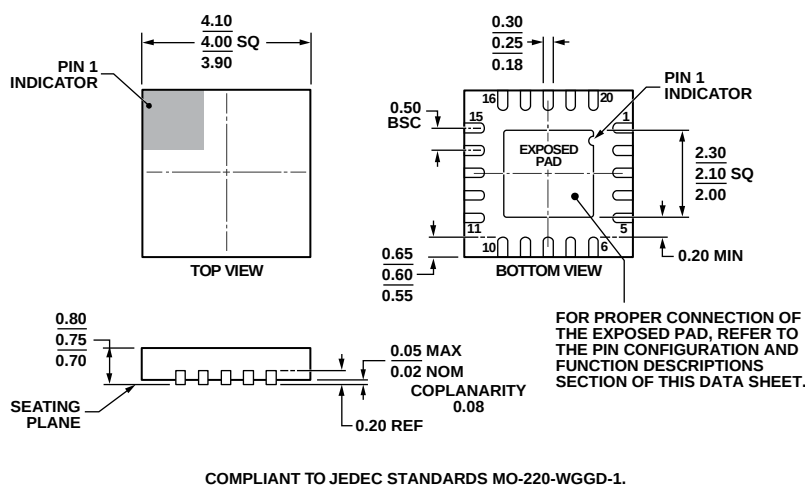


Figure 38. 20-Lead Lead Frame Chip Scale Package [LFCSP]  
4 mm × 4 mm Body and 0.75 mm Package Height  
(CP-20-6)

Dimensions shown in millimeters

## ORDERING GUIDE

| Model <sup>1</sup> | Temperature Range | Package Description                               | Package Option |
|--------------------|-------------------|---------------------------------------------------|----------------|
| ADG1233YRUZ        | −40°C to +125°C   | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16          |
| ADG1233YRUZ-REEL7  | −40°C to +125°C   | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16          |
| ADG1233YCPZ-REEL7  | −40°C to +125°C   | 16-Lead Lead Frame Chip Scale Package [LFCSP]     | CP-16-23       |
| ADG1234YRUZ        | −40°C to +125°C   | 20-Lead Thin Shrink Small Outline Package [TSSOP] | RU-20          |
| ADG1234YRUZ-REEL7  | −40°C to +125°C   | 20-Lead Thin Shrink Small Outline Package [TSSOP] | RU-20          |
| ADG1234YCPZ-REEL   | −40°C to +125°C   | 20-Lead Lead Frame Chip Scale Package [LFCSP]     | CP-20-6        |
| ADG1234YCPZ-REEL7  | −40°C to +125°C   | 20-Lead Lead Frame Chip Scale Package [LFCSP]     | CP-20-6        |

<sup>1</sup> Z = RoHS Compliant Part.